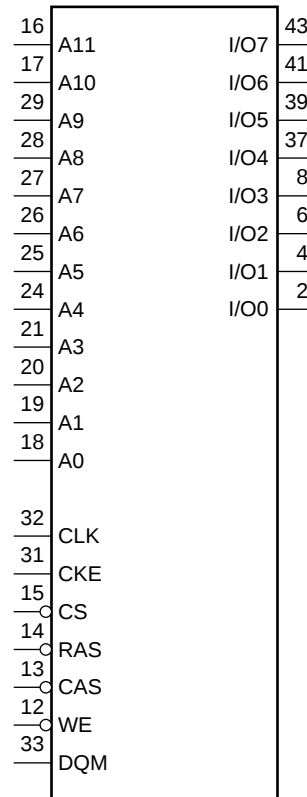
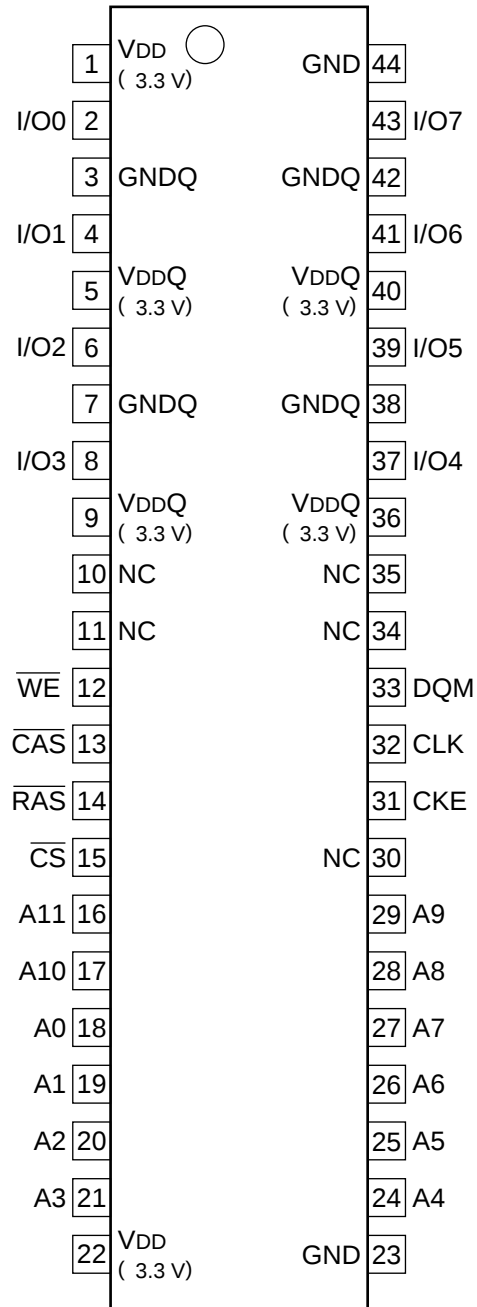

C-MOS 16 M (1,048,576 8 2)-BIT SYNCHRONOUS DYNAMIC RAM

-TOP VIEW-



INPUT

A0-A11 ; ADDRESS
 CAS ; COLUMN ADDRESS STROBE
 CKE ; CLOCK ENABLE
 CLK ; CLOCK
 CS ; CHIP SELECT
 DQM ; INPUT/OUTPUT MASK
 RAS ; ROW ADDRESS STROBE
 WE ; WRITE ENABLE

INPUT/OUTPUT

I/O0-I/O7 ; DATA

OTHER

GNDQ ; GROUND FOR I/O PIN
 VDDQ ; POWER SUPPLY FOR I/O PIN

